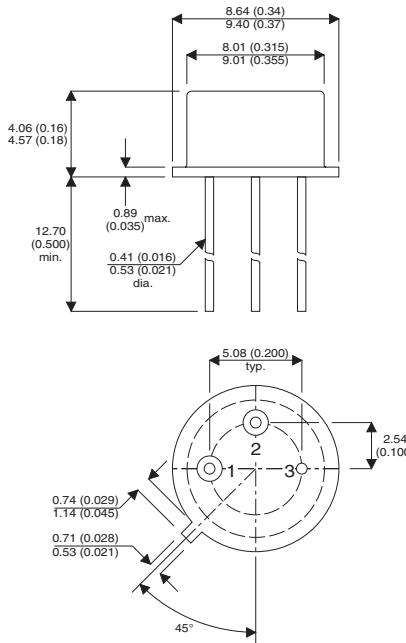


**SEME  
LAB**

**IRFF230  
2N6798**

## MECHANICAL DATA

Dimensions in mm (inches)



**TO-39 PACKAGE (TO-205AF)**

Underside View

PIN 1 – Source      PIN 2 – Gate      PIN 3 – Drain

## N-CHANNEL ENHANCEMENT MODE TRANSISTOR

### FEATURES

- $V_{(BR)DSS} = 200V$
- $I_D = 5.5A$
- $R_{DS(on)} = 0.40\Omega$

## ABSOLUTE MAXIMUM RATINGS ( $T_{case} = 25^\circ C$ unless otherwise stated)

|                |  |               |
|----------------|--|---------------|
| $V_{DS}$       | Drain–Source Voltage                               | 200V          |
| $V_{GS}$       | Gate–Source Voltage                                | $\pm 20V$     |
| $I_D$          | Drain Current Continuous $T_{Case} = 25^\circ C$   | 5.5A          |
|                | $T_{Case} = 100^\circ C$                           | 3.5A          |
| $I_{DM}$       | Drain Current Pulsed                               | 22A           |
| $P_D$          | Total Device Dissipation @ $T_{Case} = 25^\circ C$ | 25W           |
|                | $T_{Case} = 100^\circ C$                           | 10W           |
| $T_J, T_{STG}$ | Operating and Storage Junction Temperature Range   | -55 to +150°C |

### THERMAL CHARACTERISTICS

|                 |   |         |
|-----------------|---|---------|
| $R_{\theta JC}$ | Thermal Resistance Junction to Case                   | 5.0°C/W |
| $R_{\theta JA}$ | Thermal Resistance Junction to Ambient                | 175°C/W |
| $T_L$           | Maximum Lead Temperature 1.6mm from Case for 10 secs. | 300°C   |

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**ELECTRICAL CHARACTERISTICS** ( $T_J = 25^\circ\text{C}$  unless otherwise stated)

| Parameter  | Test Conditions  | Min. | Typ. | Max.      | Unit          |
|--|--|------|------|-----------|---------------|
| $V_{(\text{BR})\text{DSS}}$                      | Drain–Source Breakdown Voltage<br>$V_{GS} = 0$ $I_D = 1\text{mA}$                    | 200  |      |           | V             |
| $V_{GS(\text{th})}$                              | Gate Threshold Voltage<br>$V_{DS}=V_{GS}$ $I_D = 250\mu\text{A}$                     | 2.0  |      | 4.0       |               |
| $I_{GSS}$  | Gate–Body Leakage<br>$V_{DS} = 0$ $V_{GS} = \pm 20\text{V}$                          |      |      | $\pm 100$ | nA            |
| $I_{DSS}$  | Zero Gate Voltage Drain Current<br>$V_{DS} = 0.8 \times V_{(\text{BR})\text{DSS}}$   |      |      | 25        | $\mu\text{A}$ |
|  | $V_{GS} = 0$ $T_j = 125^\circ\text{C}$   |      |      | 250       |               |
| $r_{DS(\text{on})}$                              | Drain–Source On–Resistance <sup>1</sup><br>$V_{GS} = 10\text{V}$ $I_D = 3.5\text{A}$ |      | 0.25 | 0.4       | $\Omega$      |
| $g_{fS}$   | Forward Transconductance <sup>1</sup><br>$V_{DS} = 15\text{V}$ $I_D = 3.5\text{A}$   | 2.5  | 3.0  |           | s(Ω)          |
| $C_{iss}$  | Input Capacitance<br>$V_{DS} = 25\text{V}$ $V_{GS} = 0$                              | 600  |      |           | pF            |
| $C_{oss}$  | Output capacitance<br>$f = 1.0\text{MHz}$  | 250  |      |           |               |
| $C_{rss}$  | Reverse Transfer Capacitance   | 80   |      |           |               |
| $t_{don}$  | Turn–On Delay Time<br>$V_{DD} = 77\text{V}$ $R_L = 22\Omega$                         |      | 8    | 30        | ns            |
| $t_r$  | RiseTime<br>$I_D = 3.5\text{A}$ $V_{GEN} = 10\text{V}$                               |      | 42   | 50        |               |
| $t_{d(of)}$                                      | Turn off Delay Time<br>$R_G = 7.5 \text{ ohms}$                                      |      | 12   | 50        |               |
| $t_f$  | FallTime   |      | 30   | 40        |               |
| <b>SOURCE DRAIN DIODE RATING CHARACTERISTICS</b> |  |      |      |           |               |
| $V_{SD}$   | Diode Forward Voltage <sup>1</sup><br>$I_F = 5.5\text{A}$ $V_{GS} = 0$               |      |      | 1.4       | V             |
| $I_S$  | Continues Current  |      |      | 5.5       | A             |
| $I_{SM}$   | Pulsed Current <sup>2</sup>  |      |      | 22        |               |
| $t_{rr}$   | Reverse Recovery Time<br>$I_F = 5.5\text{A}$ $V_{DD} = 50\text{V}$                   | 150  | 500  | ns        |               |
| $Q_{rr}$   | Reverse Recovered Charge<br>$dI_F/dT = 100\text{A}/\mu\text{s}$                      |      | 6    |           | $\mu\text{C}$ |

1) Pulse test : Pulse Width < 300μs ,Duty Cycle < 2%

2) Pulse width limited by maximum juction temperature

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